

30V N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17555Q5A

FEATURES

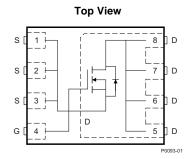
- Ultralow Q_q and Q_{qd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

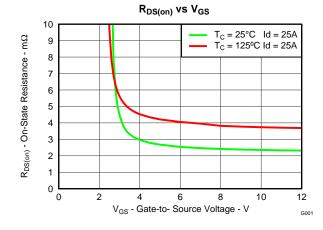
APPLICATIONS

- Point-of-Load Synchronous Buck in Networking, Telecom, and Computing Systems
- Optimized for Control and Synchronous FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.





PRODUCT SUMMARY

T _A = 25°	C unless otherwise stated	TYPICAL V	UNIT	
V_{DS}	Drain to Source Voltage 30			
Qg	Gate Charge Total (4.5V) 23 n			
Q_{gd}	Gate Charge Gate to Drain	5		nC
D	Drain to Source On Resistance	V _{GS} = 4.5V 2.8		mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	2.3	mΩ
V _{GS(th)}	Threshold Voltage	1.5	V	

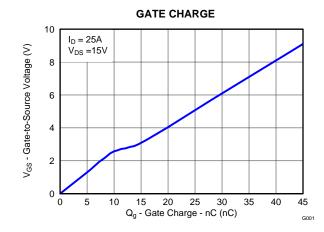
ORDERING INFORMATION

Device	Package	Media	Qty	Ship	
CSD17555Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel	

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT	
V_{DS}	Drain to Source Voltage	30	V	
V_{GS}	Gate to Source Voltage	±20	V	
	Continuous Drain Current (Package limited), $T_C = 25^{\circ}C$	100	Α	
I _D	Continuous Drain Current (Silicon limited), $T_C = 25$ °C	116	A 	
	Continuous Drain Current ⁽¹⁾	24	Α	
I_{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	153	Α	
P _D	Power Dissipation ⁽¹⁾	3	W	
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C	
E _{AS}	Avalanche Energy, single pulse $I_D=60A,\ L=0.1 mH,\ R_G=25\Omega$	180	mJ	

- (1) Typical $R_{\theta JA}=42^{\circ} C/W$ on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	haracteristics		•			
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_{DS} = 250\mu A$	30			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = 24V			1	μA
I _{GSS}	Gate to Source Leakage Current	V _{DS} = 0V, V _{GS} = 20V			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	1	1.5	1.9	V
D	Dunin to Course On Bonistano	V _{GS} = 4.5V, I _{DS} = 25A		2.8	3.4	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V, I _{DS} = 25A		2.3	2.7	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _{DS} = 25A		109		S
Dynamic	C Characteristics				<u> </u>	
C _{iss}	Input Capacitance		3875		4650	pF
C _{oss}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ $f = 1MHz$		949	1139	pF
C _{rss}	Reverse Transfer Capacitance	1 - 11/11/2		70	87	pF
R _G	Series Gate Resistance			0.8	1.6	Ω
Qg	Gate Charge Total (4.5V)			23	28	nC
Q _{gd}	Gate Charge Gate to Drain	V 45V I 25A		5		nC
Q _{gs}	Gate Charge Gate to Source	$V_{DS} = 15V, I_{DS} = 25A$		7.5		nC
Q _{g(th)}	Gate Charge at Vth		7.5			nC
Q _{oss}	Output Charge	$V_{DS} = 14V, V_{GS} = 0V$		25		nC
t _{d(on)}	Turn On Delay Time			14		ns
t _r	Rise Time	V _{DS} = 15V, V _{GS} = 4.5V,		18		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 25A, R_G = 2\Omega$		5 25 14		ns
t _f	Fall Time			5.3		ns
Diode C	haracteristics		•			
V _{SD}	Diode Forward Voltage	I _{SD} = 25A, V _{GS} = 0V		0.8	1	V
Q _{rr}	Reverse Recovery Charge	V 44V I 25A 4:/dt 2624/		31		nC
t _{rr}	Reverse Recovery Time	V_{DD} = 14V, I_F = 25A, di/dt = 300A/ μ s		25		ns
	-	L	1			

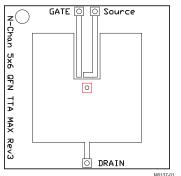
THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

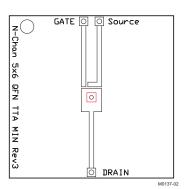
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			2.2	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			52	°C/W

 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

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Max $R_{\theta JA} = 52^{\circ}\text{C/W}$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 128^{\circ} C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

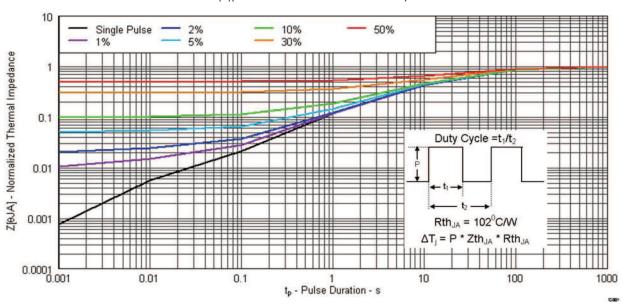


Figure 1. Transient Thermal Impedance

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TYPICAL MOSFET CHARACTERISTICS (continued)

(T_A = 25°C unless otherwise stated)

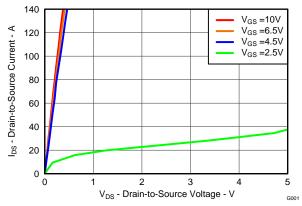
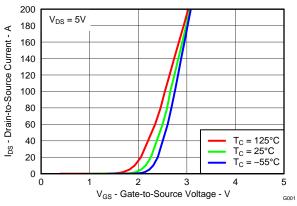


Figure 2. Saturation Characteristics



NSTRUMENTS

Figure 3. Transfer Characteristics

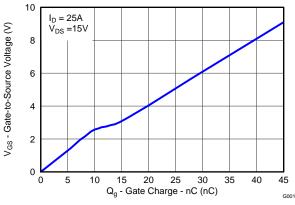


Figure 4. Gate Charge

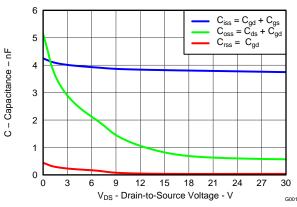


Figure 5. Capacitance

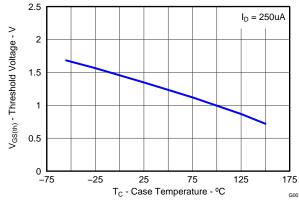


Figure 6. Threshold Voltage vs. Temperature

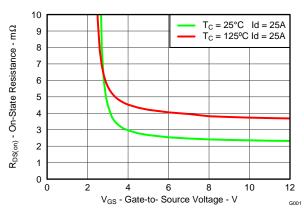


Figure 7. On-State Resistance vs. Gate-to-Source Voltage



TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25$ °C unless otherwise stated)

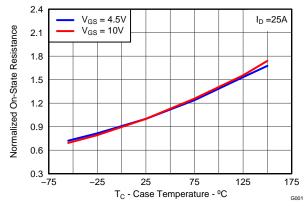


Figure 8. Normalized On-State Resistance vs. Temperature

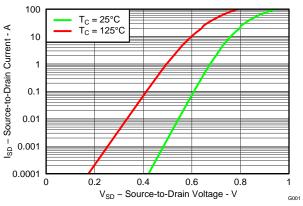


Figure 9. Typical Diode Forward Voltage

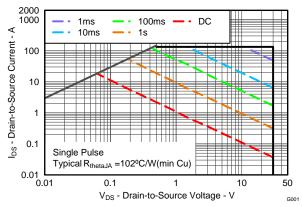


Figure 10. Maximum Safe Operating Area

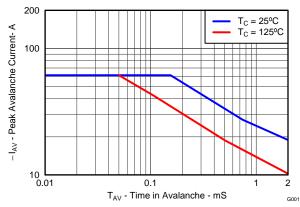


Figure 11. Single Pulse Unclamped Inductive Switching

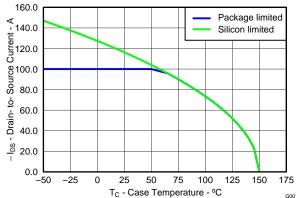


Figure 12. Maximum Drain Current vs. Temperature

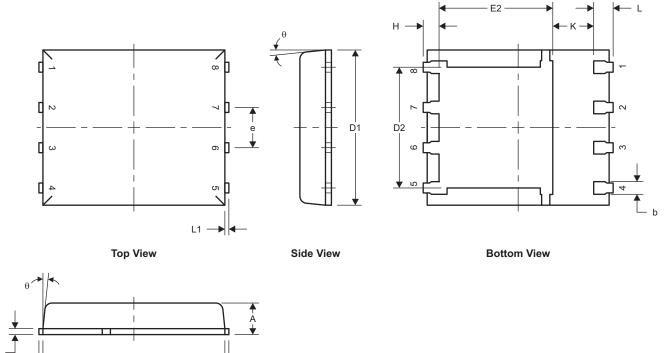
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M0135-01

MECHANICAL DATA

Q5A Package Dimensions

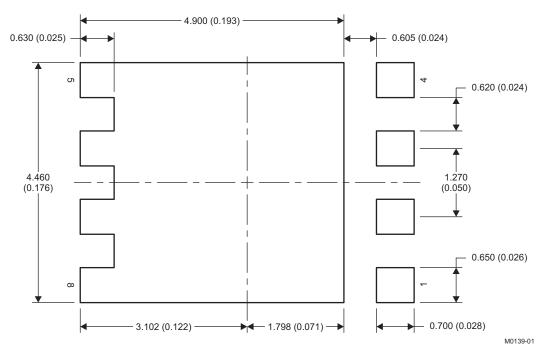


—— E1		
—— E ·	-	

Front View

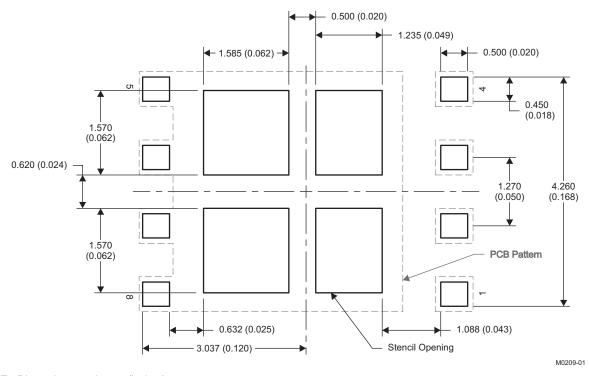
DIM		MILLIMETERS							
DIM	MIN	NOM	MAX						
А	0.90	1.00	1.10						
b	0.33	0.41	0.51						
С	0.20	0.25	0.34						
D1	4.80	4.90	5.00						
D2	3.61	3.81	4.02						
Е	5.90	6.00	6.10						
E1	5.70	5.75	5.80						
E2	3.38	3.58	3.78						
е	1.17	1.27	1.37						
Н	0.41	0.56	0.71						
К	1.10								
L	0.51	0.61	0.71						
L1	0.06	0.13	0.20						
θ	0°		12°						

Recommended PCB Pattern



NOTE: Dimensions are in mm (inches).

Stencil Recommendation



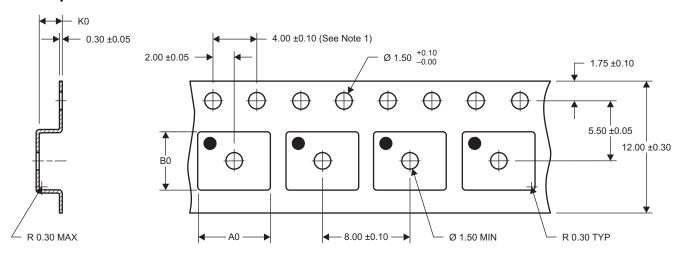
NOTE: Dimensions are in mm (inches).

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.



TEXAS INSTRUMENTS

Q5A Tape and Reel Information



 $A0 = 6.50 \pm 0.10$ $B0 = 5.30 \pm 0.10$ $K0 = 1.40 \pm 0.10$

M0138-01

- NOTES: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
 - 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
 - 3. Material: black static-dissipative polystyrene
 - 4. All dimensions are in mm (unless otherwise specified)
 - 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket



PACKAGE OPTION ADDENDUM

24-Jul-2012

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
CSD17555Q5A	ACTIVE	SON	DQJ	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ı	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD17555Q5A	SON	DQJ	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

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*All dimensions are nominal

I	Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	CSD17555Q5A	SON	DQJ	8	2500	340.0	340.0	38.0	

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